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*by* Nani Djohan1\*, Budi Harsono1, Johansah Liman1, Hen Nani Djohan1\*,  
Budi Harsono1, Johansah Liman1, Hen

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## Structural, Optical Properties and Raman Spectroscopy of In<sub>2</sub>O<sub>3</sub> Doped LiTaO<sub>3</sub> Thin Films

Nani Djohan<sup>1\*</sup>, Budi Harsono<sup>1</sup>, Johansah Liman<sup>1</sup>, Hendradi Hardhienata<sup>2</sup> and Irzaman<sup>2\*</sup>

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1 Department of Electrical Engineering, Faculty of Engineering and Computer Science, Universitas Kristen Krida Wacana, Jl. Tj. Duren Raya No.4, Jakarta 11470, Indonesia

2 Department of Physics, Faculty of Mathematics and Natural Sciences, Bogor Agricultural University, Jl. Raya Dramaga, Bogor 16680, Indonesia

### ABSTRACT

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*In this experiment, undoped, 2 wt.%, 4 wt.% and 6 wt.% In<sub>2</sub>O<sub>3</sub> doped LiTaO<sub>3</sub> thin films were successfully prepared using the Chemical Solution Deposition (CSD) method with the spin coating technique. The films were grown on the p-type Si (100) substrates with 2 M in 2-methoxyethanol precursor, whose solubility was twisted at 4000 rpm for 30 seconds. Crystalline formation of the films was carried out at annealing temperature 850 °C, held for 15 hours with temperature increment speed 1.67 ° C/min. The structural properties of the films were carried out using the XRD device with the interval of 2 theta angles from 20 to 80 degrees with a 0.02 degrees step, where thin films have formed crystals at specific angular peaks with hexagonal-shaped crystal structures. The optical properties and Raman spectra of the films were then obtained using UV-Vis spectrometer and Raman spectroscopy. From the XRD measurement, the result shows a hexagonal crystal structure with lattice parameters  $a = 5.032-5.051 \text{ \AA}$  and  $c = 13.643-13.676 \text{ \AA}$ , and from the UV-Vis data, we observed that the films have a 5.034-5.184 eV energy gap with 1.70364373 - 1.70364377 refractive index. Raman analysis produces peaks of LiTaO<sub>3</sub>, A<sub>1</sub>TO<sub>10</sub> (In<sub>2</sub>O<sub>3</sub>) and A<sub>1</sub>LO<sub>10</sub> (In<sub>2</sub>O<sub>3</sub>). Based on the characterization results, we can conclude that the LiTaO<sub>3</sub> thin films have the potential to be applied as a light sensor.*

**Keywords:** LiTaO<sub>3</sub>, In<sub>2</sub>O<sub>3</sub>, x-ray diffraction, Raman spectroscopy, uv-vis spectroscopy.

### 1. INTRODUCTION

A thin film made from Lithium tantalate (LiTaO<sub>3</sub>) is an essential optical material, mainly due to its excellent electro/acousto-optical properties, high pyroelectric coefficient, high Curie temperature, small relative dielectric constant, and good consistency of special response. The thickness of the sensitive cells is inversely proportional to the voltage response and detectivity of the detectors [1-3]. Thin layer of material whose thickness is between 10<sup>-9</sup> m and 10<sup>-6</sup> m, because of its limited thickness, the bulk material is not suitable for high-performance detection system applications [1,4]. However, LiTaO<sub>3</sub> is very attractive and promising [1,5].

There are various kinds of technology to synthesize LiTaO<sub>3</sub> thin films. X-ray Diffraction (XRD) technology is based on diffraction of X-Ray when scattering light with a wavelength passing through a crystal lattice with a distance between crystal fields. Data obtained from XRD characterization method is scattering angle (Bragg angle) to intensity. Based on diffraction theory, the diffraction angle depends on the gap of the lattice width, thus affecting the diffraction pattern. In contrast, the diffraction light intensity depends on the number of crystal lattices having the same orientation. Crystal system, parameter of the lattice, the degree of crystallinity, structure type, and orientation can be determined by this method. LiTaO<sub>3</sub> thin film with high purity and best intensity could be selected from the XRD measurement [1,6,7].

\* nani.djohan@ukrida.ac.id

\* irzaman@pps.ipb.ac.id

Solid-state and molecule vibrational properties can be analyzed by using Raman spectroscopy [8,9]; thus, strain [9,12], doping [9,13,14], stoichiometry [9,10,11] and crystallinity property information can be obtained by this technology. However, Raman spectroscopy is very sensitive to minor modifications made in the lithium tantalate compound structure, such as some frequency shifts, damping of optical phonons, or even the appearance of new lines [15]. Density functional theory (DFT) is the combination of Raman with theoretical approaches yielding phonon eigenvectors [9]. In this experiment, four types of solution ( $\text{LiTaO}_3$ ,  $\text{LiTaO}_3 + 2 \text{ wt.}\% \text{ In}_2\text{O}_3$ ,  $\text{LiTaO}_3 + 4 \text{ wt.}\% \text{ In}_2\text{O}_3$ , and  $\text{LiTaO}_3 + 6 \text{ wt.}\% \text{ In}_2\text{O}_3$ ) were produced by mixing and dissolving different molar ratios of chemical powders in the 2-methoxyethanol solvent. The films were then grown on the p-type silicon substrates utilizing spin coater and annealed at 850°C temperature. The structural and optical properties of the films were then carried out using X-Ray Diffractometer and UV-Vis spectrometer, respectively [6,7,11,16]. Furthermore, Raman spectra were carried out using Raman Spectroscopy to investigate the transversal and longitudinal phonon modes of the films [8,9,15,17-20].

## 2. MATERIAL AND METHODS

The p-type Si(100) substrates cut in size of 1x1 cm<sup>2</sup> were ultrasonically cleaned in acetone ( $\text{C}_3\text{H}_6\text{O}$ ) and repeated sequentially using methanol ( $\text{CH}_3\text{OH}$ ) and deionized water successively for 15 minutes [3,6,21-24]. The undoped  $\text{LiTaO}_3$  solution was prepared by dissolving 0.5897 gram of lithium tantalate ( $\geq 99.99\%$ , Sigma-Aldrich 704393-5G) in 2.5 ml of 2-methoxyethanol. The 2 wt.%, 4 wt.%, and 6 wt.%  $\text{In}_2\text{O}_3$  doped  $\text{LiTaO}_3$  solutions were prepared by dissolved 0.5897 gram of lithium tantalate and 0.01179 gram, 0.0236 gram, and 0.03538 gram of indium(III) oxide (99.99%, Sigma-Aldrich 289418-10G), respectively in 2.5 ml of 2-methoxyethanol.

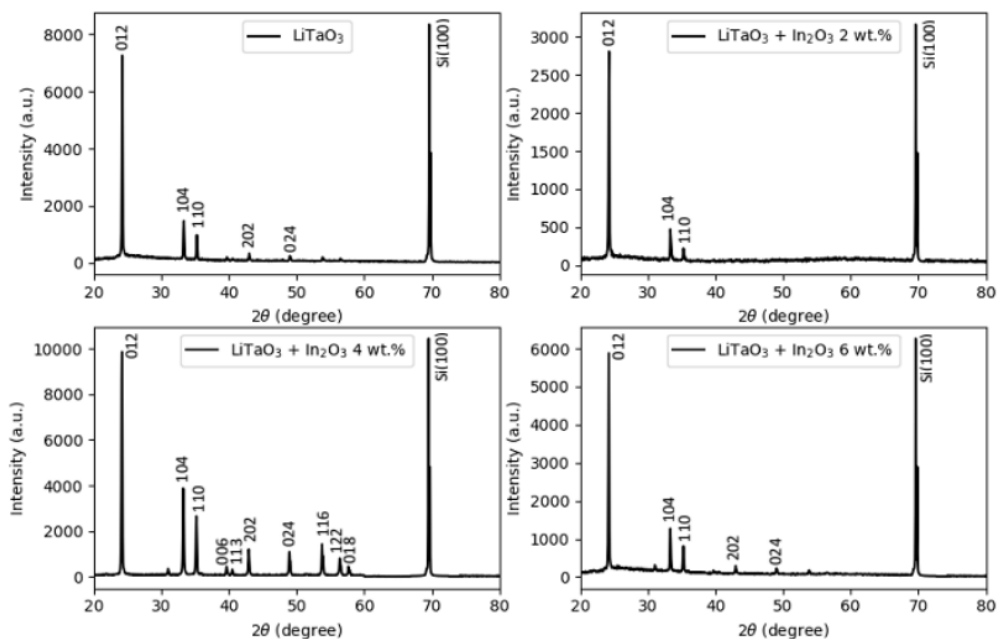
To get the homogeneous  $\text{LiTaO}_3$  solutions, the solutions were stirred using Vortex 3000 mixer and then sonicated using an ultrasonicator device (J.P Selecta) for 30 minutes [3,6]. Furthermore, the thin films were deposited on the p-type Si (100) substrates using spin coater for 30 seconds using a rotating speed of 4000 rpm. This process was repeated three times with a one-minute time interval [3,4,6,16,21-26]. The annealing process was done using Nabertherm B410 furnace at temperature 850°C for 15 hours, with a temperature increment speed of 1.67°C/min. The structural properties of the thin-film crystal were then obtained with an X-Ray Diffractometer (Bruker D2 PHASER). Furthermore, the thin films were characterized by using a UV-Vis spectrometer (Ocean Optics USB4000-UV-Vis) and Raman spectroscopy (Horriba iHR550).

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## 3. RESULTS AND DISCUSSION

### 3.1 Structural properties

The XRD patterns of  $\text{LiTaO}_3$  thin films were determined from  $20^\circ \leq 2\theta \leq 80^\circ$  intervals with a scanning rate of 0.02°/minute [6,11,27-29]. Figure 1 shows the XRD patterns of undoped and  $\text{In}_2\text{O}_3$  doped  $\text{LiTaO}_3$  thin films [6,11,27]. The Miller index values were assigned by referring to the standard x-ray diffraction powder patterns file (JCPDS Natl Bur, 1977) and were in good agreement with the values reported in the file. The XRD patterns showed that  $\text{LiTaO}_3$  thin films were both amorphous and crystalline with hexagonal crystal structure. All the XRD patterns showed a preferred strong peak at (012) diffraction plane. The peaks profiles of the two most dominant peaks at (012) and (104) diffraction plane was obtained by Gaussian fitting. Peak position ( $2\theta$ ) and the full width at half maximum (FWHM) from the peaks are shown in Table 1.



10 **Figure 1.** XRD patterns of LiTaO<sub>3</sub> thin films with different doped In<sub>2</sub>O<sub>3</sub> at annealing temperature 850°C.

The crystallite size (D) of the undoped and In<sub>2</sub>O<sub>3</sub> doped LiTaO<sub>3</sub> thin films was calculated using Debye Scherer's formula.

$$D = \frac{k\lambda}{\beta \cos\theta} \quad (1)$$

16 Where k is the shape factor (= 0.9), λ is the X-ray radiation wavelength (= 0.15406 nm), β is FWHM of diffraction peak in radian, and θ is the Bragg's diffraction angle in radian. The highest crystallite size values observed were 51.408 nm and 46.620 nm for (012) and (104) diffraction plane in 6 wt.% In<sub>2</sub>O<sub>3</sub> doped LiTaO<sub>3</sub> thin film. The crystallite size decreased in line with the decrease in doping concentration, as shown in Table 1.

The dislocation density (δ) of the undoped and In<sub>2</sub>O<sub>3</sub> doped LiTaO<sub>3</sub> thin films could be obtained using the Williamson-Smallman formula.

$$\delta = \frac{1}{D^2} \quad (2)$$

Where D is the crystallite size of the films obtained from Eq.1, it was observed that the dislocation density decreases as doping concentration increases.

The lattice strain (ε) of the undoped and In<sub>2</sub>O<sub>3</sub> doped LiTaO<sub>3</sub> thin films was calculated by using the following formula.

$$\varepsilon = \frac{\beta}{4 \tan \theta} \quad (3)$$

The data show that when doping concentration increases beyond 2 wt.%, lattice strain will decrease. This suggests the creation of fewer defects in the LiTaO<sub>3</sub> lattice. All the calculated results from the XRD data are shown in Table 1.

The interplanar spacing ( $d_{hkl}$ ) for each peak can be calculated using Bragg's formula, as shown in Eq. 4. The lattice parameters ( $a$  and  $c$ ) can be calculated from the interplanar spacing equation for hexagonal lattice as shown in Eq. 5, where  $hkl$  is the Miller indices of the plane of diffraction.

$$d_{hkl} = \frac{\lambda}{2\sin\theta} \quad (4)$$

$$\frac{1}{d_{hkl}^2} = \frac{4}{3} \left( \frac{h^2 + hk + k^2}{a^2} \right) + \frac{l^2}{c^2} \quad (5)$$

The calculated lattice parameters for undoped and various wt.%  $\text{In}_2\text{O}_3$  doped  $\text{LiTaO}_3$  thin films are tabulated in Table 2. From the data in table 2, the calculated lattice parameters were slightly different from the JCPDS data due to differences in annealing temperature.

**Table 1** Crystallite size, dislocation density, and lattice strain of  $\text{LiTaO}_3$  thin films doped with  $\text{In}_2\text{O}_3$

Sample	Diffraction plane	2 $\theta$ (deg)	FWHM (deg)	Crystallite size (nm)	Dislocation density ( $\text{cm}^{-2}$ ) $\times 10^{10}$	Lattice strain $\times 10^{-3}$
$\text{LiTaO}_3$	0 1 2	24.186	0.160	50.805	3.874	3.257
	1 0 4	33.293	0.197	42.001	5.669	2.881
$\text{LiTaO}_3 + 2 \text{ wt.}\% \text{In}_2\text{O}_3$	0 1 2	24.217	0.167	48.638	4.227	3.398
	1 0 4	33.333	0.197	42.016	5.665	2.877
$\text{LiTaO}_3 + 4 \text{ wt.}\% \text{In}_2\text{O}_3$	0 1 2	24.131	0.160	50.685	3.893	3.272
	1 0 4	33.231	0.189	43.834	5.204	2.765
$\text{LiTaO}_3 + 6 \text{ wt.}\% \text{In}_2\text{O}_3$	0 1 2	24.187	0.158	51.408	3.784	3.218
	1 0 4	33.293	0.178	46.620	4.601	2.596

**Table 2** Lattice parameter values of  $\text{LiTaO}_3$  thin films doped with  $\text{In}_2\text{O}_3$  hexagonal structure

Lattice parameter	$\text{LiTaO}_3$	$\text{LiTaO}_3 + 2 \text{ wt.}\% \text{In}_2\text{O}_3$	$\text{LiTaO}_3 + 4 \text{ wt.}\% \text{In}_2\text{O}_3$	$\text{LiTaO}_3 + 6 \text{ wt.}\% \text{In}_2\text{O}_3$	JCPDS (Natl Bur, 1977)
c (Å)	13.658	13.643	13.676	13.658	13.755
a (Å)	5.038	5.032	5.051	5.038	5.153

### 3.2 Optical properties

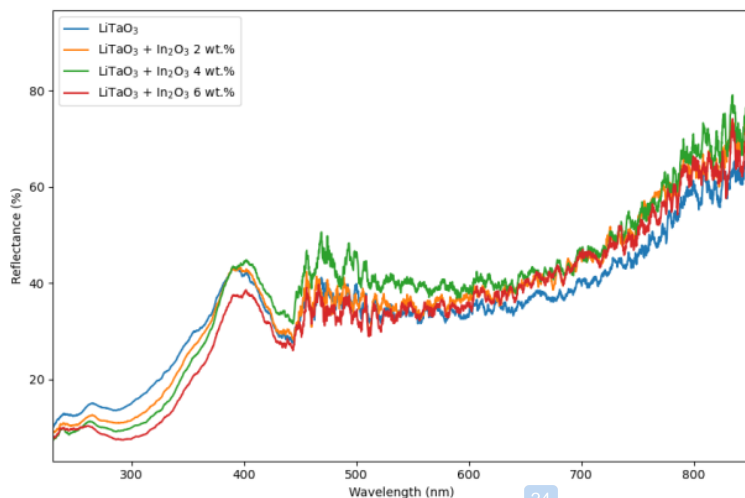
The optical properties of the undoped and  $\text{In}_2\text{O}_3$  doped  $\text{LiTaO}_3$  thin films were investigated by analyzing the reflectance spectra in the wavelength between 230 nm and 850 nm (UV-Vis range). The reflectance spectra of the synthesized films are shown in figure 2. In the reflectance spectra, we observed that the films have low reflectance in the ultra-violet range and high reflectance in the visible range. We could estimate the band gap energy ( $E_g$ ) values of the synthesized films from the reflectance spectra. The recorded reflectance spectra were first transformed to the absorption spectra by applying the Kubelka-Munk function ( $F(R)$ ). Then the Tauc plot method is employed to determine the band gap energy [3,6,32]. The Kubelka-Munk function and the Tauc formula are given in Eq.6 dan Eq.7, respectively.

$$F(R) = \frac{K}{S} = \frac{(1-R)^2}{2R} \propto \alpha_{K-M} \quad (6)$$

$$(\alpha_K - Mh\nu)^{1/n} = B(h\nu - E_g) \quad (7)$$

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K and S are absorption and scattering coefficients, respectively. R is reflectance value,  $h\nu$  is the photon's energy, B is a constant,  $E_g$  is the band gap energy, and n is the nature of the electron transition ( $= \frac{1}{2}$  for direct transition band gap).

From the Tauc plot, it is found that the optical band gap energy of undoped, 2 wt.%, 4 wt.%, and 6 wt.%  $\text{In}_2\text{O}_3$  doped  $\text{LiTaO}_3$  thin films are 5,034 eV, 5,079 eV, 5,122 eV, and 5,184 eV, respectively, as shown in figure 3. From the data, it was observed that the increase in doping concentration also increased the band gap energy of the films.



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Figure 2. Reflectance spectra of  $\text{LiTaO}_3$  thin films.

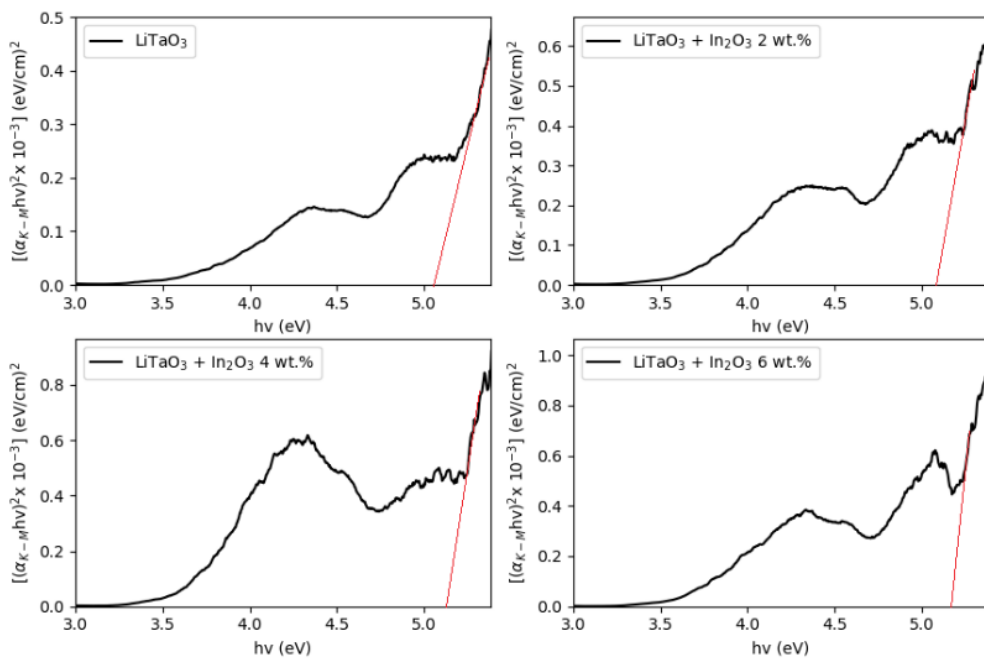


Figure 3. Energy band gap of  $\text{LiTaO}_3$  thin films.

Refractive index ( $n_e$ ) of the films were obtained by using Sellmeier formula[6,33,34].

$$n_e^2(\lambda, T) = A + \frac{B+b(T)}{\lambda^2-[c+c(T)]^2} + \frac{E}{\lambda^2-F^2} + \frac{G}{\lambda^2-H^2} + D\lambda^2 \quad (8)$$

Where  $\lambda$  is the wavelength related to the band gap energy value,  $b(T)$ ,  $c(T)$  is the temperature dependent, and  $A, B, C, D, E, F, G, H$  is the coefficients of Sellmeier. The data show that the value of the refractive index also increase as the band gap energy increased. The refractive index, band gap energy and related color spectra of undoped, 2 wt.%, 4 wt.%, and 6 wt.%  $\text{In}_2\text{O}_3$  doped  $\text{LiTaO}_3$  thin films were listed in Table 3.

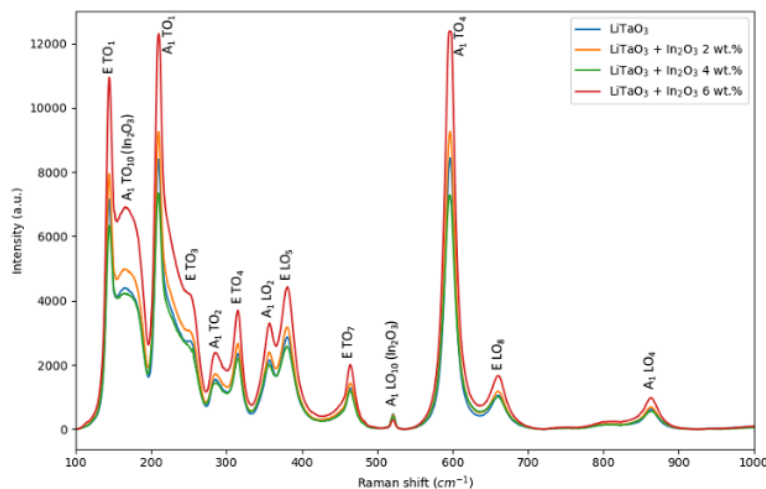
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**Table 3** The energy gap and the refractive index of  $\text{LiTaO}_3$  thin films

Sample	Band gap (eV)	Wavelength (nm)	Color spectra	Refractive index
<b>LiTaO<sub>3</sub></b>	5.034	246.855	ultraviolet	1.70364373
<b>LiTaO<sub>3</sub> + 2 wt.% In<sub>2</sub>O<sub>3</sub></b>	5.079	244.692	ultraviolet	1.70364374
<b>LiTaO<sub>3</sub> + 4 wt.% In<sub>2</sub>O<sub>3</sub></b>	5.122	242.529	ultraviolet	1.70364375
<b>LiTaO<sub>3</sub> + 6 wt.% In<sub>2</sub>O<sub>3</sub></b>	5.184	239.715	ultraviolet	1.70364377

### 3.3 Raman Spectrum

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Raman spectroscopy technology can be used to mapping demonstrates a spatial variation of the widths of the phonon bands for stoichiometric, congruent, and quasi-congruent samples. To investigate the compositional uniformity of these crystals, we use Raman spectra of  $\text{LiTaO}_3$  single crystals with various stoichiometric [8,9,15]. The first principles, the peaks of Raman intensity were assigned by referring to the mode energy [9,30,31]. The phonons identification may become complicated because some Raman intensity might be lost on the calculated modes [9]. Longitudinal phonon mode was observed when polarization vectors and phonon wave vector are parallel, whereas transversal phonon mode was observed when polarization vectors and phonon wave vector are perpendiculars.

Figure 4 shows the Raman spectrum of undoped, 2 wt.%, 4 wt.%, and 6wt.%  $\text{In}_2\text{O}_3$  doped  $\text{LiTaO}_3$  thin films. In this experiment, Raman spectra were obtained by Raman spectroscopy in the range from 100 to 1000  $\text{cm}^{-1}$ .



**Figure 4.** Raman spectroscopy of  $\text{LiTaO}_3$ .

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Table 4 shows the result of active phonon frequencies of undoped, 2%, 4%, and 6% In<sub>2</sub>O<sub>3</sub> doped LiTaO<sub>3</sub> thin films. The experiment results show that the most significant deviation is 5 cm<sup>-1</sup> at A<sub>1</sub> TO<sub>4</sub> and the mean deviation is 1.82 cm<sup>-1</sup>.

**Table 4** Theory and experiment result of active phonon frequencies of LiTaO<sub>3</sub>

Symmetry	Mode	Exp.	Literature [9]	Mode	Exp.	Literature [9]
A <sub>1</sub>	TO1	209	209	LO1		255
A <sub>1</sub>	TO2	285	286	LO2	356	355
A <sub>1</sub>	TO3		376	LO3		403
A <sub>1</sub>	TO4	596	591	LO4	863	866
E	TO1	144	144	LO1		190
E	TO2		199	LO2		
E	TO3	253	253	LO3		279
E	TO4	315	319	LO4		
E	TO5		409	LO5	380	381
E	TO6		420	LO6		453
E	TO7	463	459	LO7		
E	TO8		590	LO8	661	660
E	TO9		669	LO9		866
A <sub>1</sub>	TO10	165		LO10	521	

Phonon activities in hexagonal crystal structures (XRD analysis) and electron jump from valence band into induction band to become free electron (UV-Vis analysis) leads to the occurrence of transversal and longitudinal mode (Raman spectroscopy) and electron free radicals on the thin film surface. The intensity difference of the free radicals shown in Raman spectroscopy (Figure 4) is caused by In<sup>3+</sup> doping and radius in the LiTaO<sub>3</sub> thin films.

#### 4. CONCLUSION

The making of In<sub>2</sub>O<sub>3</sub> doped LiTaO<sub>3</sub> thin films with CSD method was succeeded. Analysis of the thin films was conducted using XRD, UV-Vis spectrometer and Raman spectroscopy. Based on the characterization result, we can be concluded that the LiTaO<sub>3</sub> thin films have the potential to be applied as a light sensor, especially in the ultraviolet region.

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